



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	14.22	14.99	0.560	0.590
B	9.77	10.54	0.385	0.415
C	4.06	4.82	0.160	0.190
D	0.58	0.94	0.023	0.037
E	1.14	1.40	0.045	0.055
F	13.72	14.10	0.540	0.555
G	1.27	BSC	0.050	BSC
H	14.48	15.11	0.570	0.595
J	0.36	0.56	0.014	0.022
K	19.94	20.32	0.785	0.800
L	8.18	8.56	0.322	0.337
M	1.85	2.24	0.073	0.088
N	2.28	2.91	0.090	0.115
Q	3.70	3.95	0.146	0.156
R	7.34	7.72	0.289	0.304
S	4.17	4.55	0.164	0.179
U	11.68	12.07	0.460	0.475
W	3°		3°	

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION D DOES NOT INCLUDE INTERCONNECT BAR (DAM BAR) PROTRUSION. DIMENSION D INCLUDING PROTRUSION SHALL NOT EXCEED 10.92(0.043) MAXIMUM.
4. 821J-01 OBSOLETE. NEW STANDARD IS 821J-02.

CASE NO.	821J-02
STATUS	ON SEMICONDUCTOR STANDARD
NEW STD	
USED ON	



ISSUE	REVISION	COORD/ DATE
0	INITIAL RELEASE REQ BY T. GRINTER	FB 04 AUG 00
A	ADDED MISSING DIM H IN TABLE. REQ BY F. PADILLA	FB 18 OCT 00